



### 30V P-Channel Enhancement Mode MOSFET

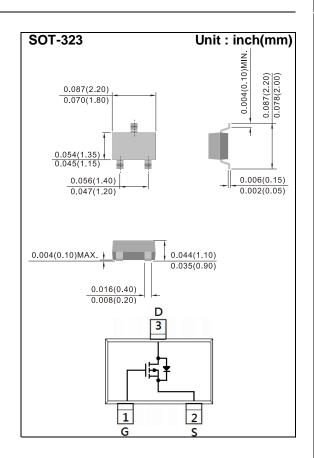
Voltage -30 V Current -1.5A

#### **Features**

- RDS(ON), VGS@-10V, ID@-1.5A<115mΩ
- RDS(ON), VGS@-4.5V, ID@-1.1A<130mΩ</li>
- RDS(ON) , VGS@-2.5V, ID@-0.6A<180mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: SOT-323 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00018 ounces, 0.005 grams
- Marking: C01



# **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAME	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	-30	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 12	V
Continuous Drain Current		I <sub>D</sub>	-1.5	Α
Pulsed Drain Current		I <sub>DM</sub>	-6	Α
Power Dissipation	T <sub>a</sub> =25°C	)	350	mW
	Derate above 25°C	$P_{D}$	2.8	mW/°C
Operating Junction and Storage	$T_J, T_{STG}$	-55~150	°C	
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	357	°C/W





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	ı	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-0.5	-0.96	-1.3	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-1.5A	-	105	115	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-1.1A	-	115	130	
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-0.6A	-	145	180	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-15V, I <sub>D</sub> =-1.5A, V <sub>GS</sub> =-10V <sup>(Note 1,2)</sup>	-	11	-	nC
Gate-Source Charge	$Q_gs$		-	0.85	ı	
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =-10V	-	1.4	-	
Input Capacitance	Ciss	15)/ )/ 0)/	-	443	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	38	-	
Reverse Transfer Capacitance	Crss	I=1.UIVINZ	-	25	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>	\/ 45\/ L 45A	-	2.5	-	ns
Turn-On Rise Time	tr	V <sub>DD</sub> =-15V, I <sub>D</sub> =-1.5A,	-	32	-	
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =-10V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	161	-	
Turn-Off Fall Time	tf	K <sub>G</sub> =012	-	73	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	I <sub>S</sub>		_	-	-0.5	Α
Diode Forward Current						
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-1A, V <sub>GS</sub> =0V	-	-0.79	-1.2	V

### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





#### **TYPICAL CHARACTERISTIC CURVES**

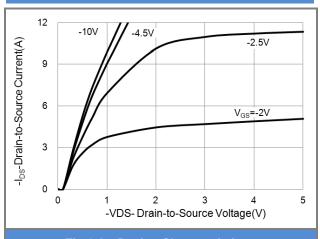
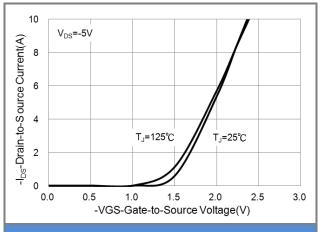


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

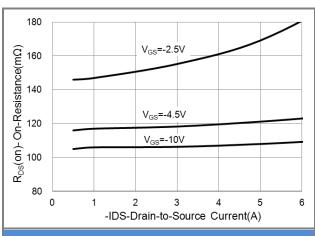


Fig.3 On-Resistance vs. Drain Current

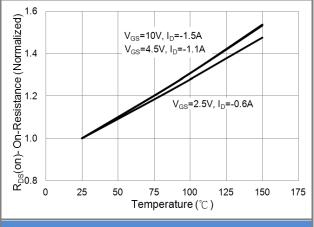


Fig.4 On-Resistance vs. Junction temperature

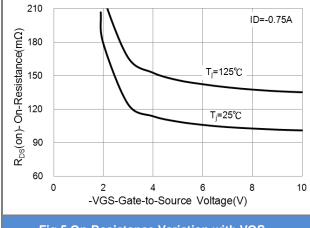
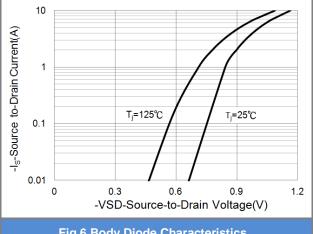


Fig.5 On-Resistance Variation with VGS.



**Fig.6 Body Diode Characteristics** 





### **TYPICAL CHARACTERISTIC CURVES**

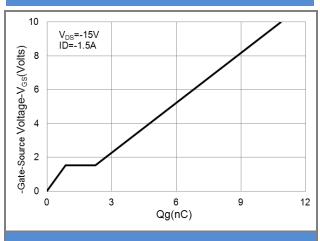


Fig.7 Gate-Charge Characteristics

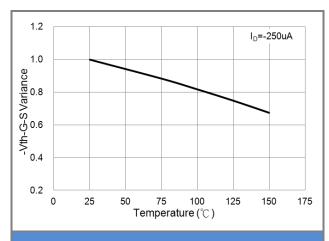


Fig.8 Threshold Voltage Variation with Temperature.

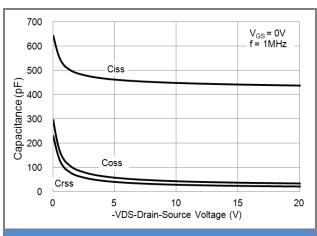


Fig.9 Capacitance vs. Drain-Source Voltage.

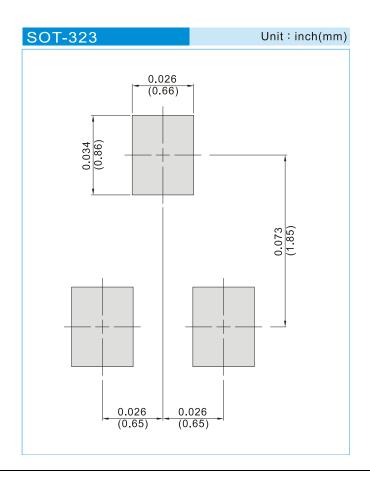




### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJC7401_R1_00001	SOT-323	3K pcs / 7" reel	C01	Halogen free
PJC7401_R2_00001	SOT-323	12K pcs / 13" reel	C01	Halogen free

### **MOUNTING PAD LAYOUT**







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